

Operational Amplifiers

LM308 operational amplifier

general description

The LM308 is a precision operational amplifier featuring input currents nearly a thousand times lower than industry standards like the LM709C. In fact, its performance approaches that of high quality FET amplifiers. The circuit is directly interchangeable with the LM301A in low frequency circuits and incorporates the same protective features which make its application nearly foolproof.

The device operates with supply voltages from $\pm 2V$ to $\pm 15V$ and has sufficient supply rejection to use unregulated supplies. Although the circuit is designed to work with the standard compensation for the LM301A, an alternate compensation scheme can be used to make it particularly insensitive to power supply noise and to make supply bypass capacitors unnecessary. Power consumption is extremely low, so the amplifiers are ideally suited for battery powered applications. Out-

standing characteristics include:

- Maximum input bias current of 7.0 nA
- Offset current less than 1.0 nA
- Supply current of only 300 μA, even in saturation
- Guaranteed drift characteristics

The low current error of the LM308 makes possible many designs that are not practical with conventional amplifiers. In fact, it operates from 10 M\Omega source resistances, introducing less error than devices like the 709C with 10 k\Omega sources. Integrators with worst case drifts less than 1 mV/sec and analog time delays in excess of one hour can be made using capacitors no larger than 1 μ F. The device is well suited for use with piezo-electric, electrostatic or other capacitive transducers, in addition to low frequency active filters with small capacitor values.





 v_{in} v_{in} v

Alternate* Frequency Compensation



85

absolute maximum ratings

Supply Voltage	±18V
Power Dissipation (Note 1)	500 mW
Differential Input Current (Note 2)	±10 mA
Input Voltage (Note 3)	±15V
Output Short-Circuit Duration	Indefinite
Operating Temperature Range	0°C to 70°C
Storage Temperature Range	–65°C to 150°C
Lead Temperature (Soldering, 60 sec)	300°C

electrical characteristics (Note 4)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Input Offset Voltage	$T_A = 25^{\circ}C$		2.0	7.5	mV	
Input Offset Current	T _A = 25°C		0.2	1	nA	
Input Bias Current	T _A = 25°C		1.5	7	nA	
Input Resistance	T _A = 25°C	10	40		MS2	
Supply Current	T _A = 25°C, V _S = ±15V		0.3	0.8	mA	
Large Signal Voltage Gain	$T_A = 25^{\circ}C, V_S = \pm 15V$ $V_{OUT} = \pm 10V, R_L \ge 10 k \Omega$	25	300		V/mV	
Input Offset Voltage				10	mV	
Average Temperature Coefficient of Input Offset Voltage			6.0	30	µV/°C	
Input Offset Current				1.5	nA	
Average Temperature Coefficient of Input Offset Current			2.0	10	pA/°C	
Input Bias Current				10	nA	
Large Signal Voltage Gain	V _S = ±15V, V _{OUT} = ±10V R _L ≥ 10 kΩ	15			V/mV	
Output Voltage Swing	$V_s = \pm 15V, R_L = 10 k\Omega$	±13	±14		v	
Input Voltage Range	V _S = ±15V	±14			v	
Common Mode Rejection Ratio		80	100		dB	
Supply Voltage Rejection Ratio		80	96		dB	

Note 1: The maximum junction temperature of the LM308 is 85° C. For operating at elevated temperatures, devices in the TQ-5 package must be derated based on a thermal resistance of 150 C/W, junction to ambient, or 45° C/W, junction to case. For the flat package, the derating is based on a thermal resistance of 185 C/W when mounted on a 1/16-inch-thick epoxy glass board with ten, 0.03-inch-wide, 2-ounce copper conductors. The thermal resistance of the dual-in-line package is 100 C/W, junction to ambient.

Note 2: The inputs are shunted with back-to-back diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

Note 3: For supply voltages less than $\pm 15V$, the absolute maximum input voltage is equal to the supply voltage.

Note 4: These specifications apply for $\pm 5V \leq V_S \leq \pm 15V$ and $0^{\circ}C \leq T_A \leq 70^{\circ}C$, unless otherwise specified.



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